



30V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(on) max} | Ι _D Τ _A = 25°C |
|----------------------|--------------------------------|--|
| | $50m\Omega @ V_{GS} = -10V$ | -3.7A |
| -30V | 60mΩ @ V _{GS} = -4.5V | -3.3A |
| | 85mΩ @ V_{GS} = -2.5V | -2.7A |

Description

This new generation Small-Signal enhancement mode MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

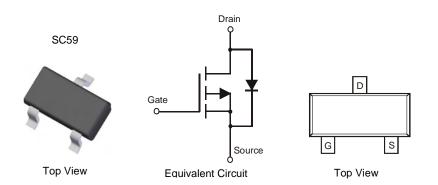
- Motor control
- Backlighting
- DC-DC Converters
- Power management functions

Features

- Low Input Capacitance
- Low On-Resistance
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SC59
- Case Material: Molded Plastic "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|--------------|------|------------------|
| DMG3401LSN-7 | SC59 | 3000/Tape & Reel |

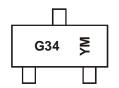
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



G34 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

| Date Code Rey | | | | | | | | | | | | |
|---------------|-------------------------|-----|------|-----|------|-----|-----|------|-----|------|-----|------|
| Year | 201 ² | 1 | 2012 | | 2013 | 20 | 14 | 2015 | | 2016 | 2 | 2017 |
| Code | Y | | Z | | А | E | 3 | С | | D | | E |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Units |
|--|------------------|--|----------------|--------------|-------|
| Drain-Source Voltage | V _{DSS} | -30 | V | | |
| Gate-Source Voltage | V _{GSS} | ±12 | V | | |
| Continuous Drain Current (Note 5) V _{GS} = -10V | Steady State | T _A = +25°C T _A = +70°C | ID | -3.0 -2.3 | A |
| Continuous Drain Current (Note 6) V _{GS} = -10V | Steady State | T _A = +25°C T _A = +70°C | Ι _D | -3.7 -2.9 | А |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | I _{DM} | -30 | А | | |
| Maximum Body Diode Continuous Current (Note 6) | I _S | -1.5 | А | | |

Thermal Characteristics

| Characteristic | | Symbol | Value | Units | |
|---|----------|----------------------------------|-------------|-------|--|
| Tatal Dowar Dissipation | (Note 5) | 0 | 0.8 | W | |
| Total Power Dissipation | (Note 6) | PD | 1.2 | VV | |
| Thermel Desistance, lunction to Ambient | (Note 5) | D | 159 | | |
| Thermal Resistance, Junction to Ambient | (Note 6) | $R_{	extsf{	heta}JA}$ | 105 | °C/W | |
| Thermal Resistance, Junction to Case | (Note 6) | R _θ JC | 36 | | |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|------|------|------|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | • | - | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | - | - | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current T _J = 25°C | I _{DSS} | - | - | -1.0 | μA | $V_{DS} = -30V, V_{GS} = 0V$ |
| Gate-Body Leakage | IGSS | - | - | ±100 | nA | $V_{GS} = \pm 12V$, $V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -0.5 | -1.0 | -1.3 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ |
| | | - | 41 | 50 | | $V_{GS} = -10V, I_D = -4A$ |
| Static Drain-Source On-Resistance | R _{DS (ON)} | - | 47 | 60 | mΩ | $V_{GS} = -4.5V, I_D = -3.5A$ |
| | | - | 60 | 85 | | V _{GS} = -2.5V, I _D = -2.5A |
| Forward Transfer Admittance | Y _{fs} | - | 12 | - | S | $V_{DS} = -5V, I_D = -4A$ |
| Diode Forward Voltage | V _{SD} | - | -0.8 | -1.0 | V | $V_{GS} = 0V, I_{S} = -1A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | - | 1326 | - | | |
| Output Capacitance | Coss | - | 103 | - | pF | $V_{DS} = -15V, V_{GS} = 0V, f = 1.0MHz$ |
| Reverse Transfer Capacitance | C _{rss} | - | 71 | - | | |
| Gate Resistance | Rg | - | 7.3 | - | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ |
| Total Gate Charge (V _{GS} = -4.5V) | Qg | - | 11.6 | - | | |
| Total Gate Charge (V _{GS} = -10V) | Qq | - | 25.1 | - | | |
| Gate-Source Charge | Q _{gs} | - | 2 | - | nC | $V_{DD} = -15V, I_D = -4A$ |
| Gate-Drain Charge | Q _{qd} | - | 1.7 | - | | |
| Turn-On Delay Time | t _{D(on)} | - | 8 | - | | |
| Turn-On Rise Time | tr | - | 13 | - | | V _{DS} = -15V, V _{GS} = -10V, |
| Turn-Off Delay Time | t _{D(off)} | - | 71 | - | nS | $R_{GEN} = 6\Omega, R_L = 3.75\Omega$ |
| Turn-Off Fall Time | tf | - | 38 | - | 1 | |

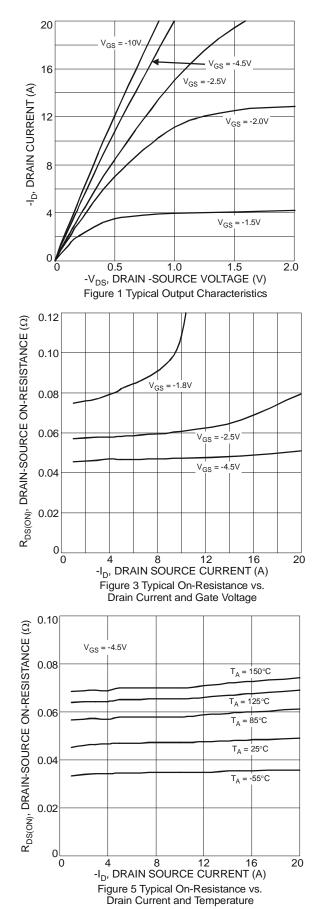
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

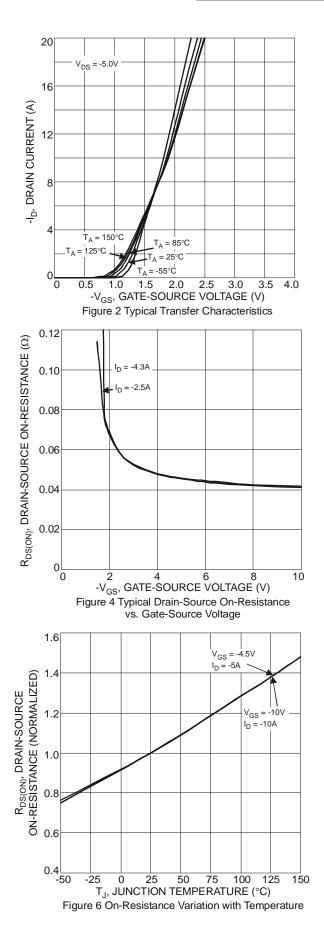
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout

Source duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing

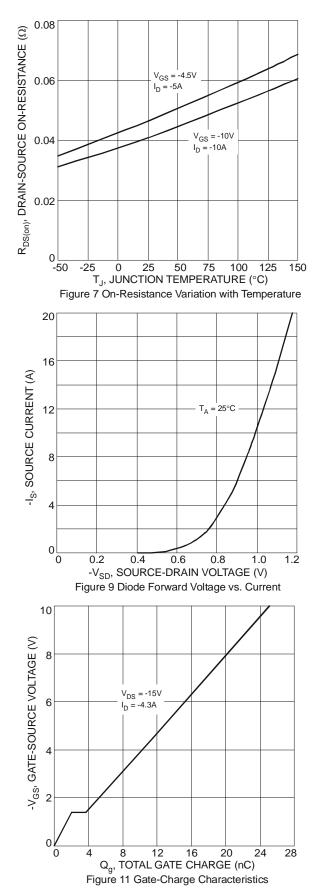
Notes:

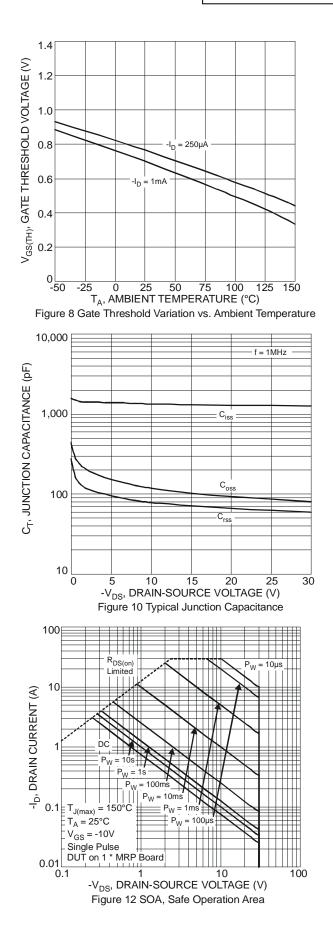




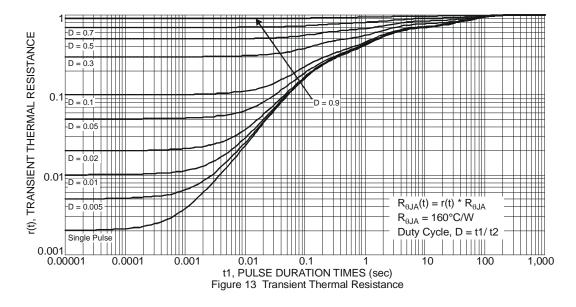






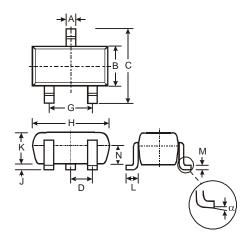






Package Outline Dimensions

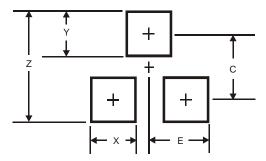
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| | SC59 | | | | | | | |
|----------------------|-------|------|------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.35 | 0.50 | 0.38 | | | | | |
| В | 1.50 | 1.70 | 1.60 | | | | | |
| С | 2.70 | 3.00 | 2.80 | | | | | |
| D | - | - | 0.95 | | | | | |
| G | - | - | 1.90 | | | | | |
| Н | 2.90 | 3.10 | 3.00 | | | | | |
| J | 0.013 | 0.10 | 0.05 | | | | | |
| к | 1.00 | 1.30 | 1.10 | | | | | |
| L | 0.35 | 0.55 | 0.40 | | | | | |
| М | 0.10 | 0.20 | 0.15 | | | | | |
| Ν | 0.70 | 0.80 | 0.75 | | | | | |
| α | 0° | 8° | - | | | | | |
| All Dimensions in mm | | | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 3.4 |
| Х | 0.8 |
| Y | 1.0 |
| С | 2.4 |
| E | 1.35 |



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